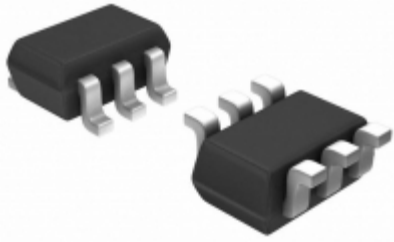

	SI1967DH-T1-GE3
	Hersteller-Teilenummer: SI1967DH-T1-GE3
	Hersteller / Marke: Vishay / Siliconix
	Teil der Beschreibung: MOSFET 2P-CH 20V 1.3A SC70-6
Datenblätter:  SI1967DH-T1-GE3.pdf	RoHs Status: Bleifrei / RoHS-konform
Lagerzustand: New original, 12000 pcs Stock Available.	Liefern von: Hong Kong
Image may be representation. See specs for product details.	Versandweg: DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	SI1967DH-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2P-CH 20V 1.3A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	12000 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.25W
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.3A
Rds On (Max) @ Id, Vgs	490 mOhm @ 910mA, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	4nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	110pF @ 10V
Verpackung	Tape & Reel (TR)




SI1967DH-T1-GE3 ist neu im Original, Suche SI1967DH-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1967DH-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1967DH-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1970DH-T1-E3 Vishay / Siliconix MOSFET 2N-CH 30V 1.3A SC70-6</p>	 <p>SI1970DH-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 30V 1.3A SC70-6</p>	 <p>SI1967DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 1.3A SC70-6</p>	 <p>SI1970DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 1.3A SC70-6</p>
 <p>SI1967DH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 1.3A SC70-6</p>	 <p>SI1967DH-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 1.3A SC70-6</p>	 <p>SI1969DH-E3 VISHAY SI1969DH-E3 VISHAY</p>	 <p>SI1965DH-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 12V 1.3A SC70-6</p>

heiße Teile

Mehr

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|--|--|--|--|--|
|  SI1905DL-T1 |  SI1905DL-T1-E3 |  SI1905DL-T1-E3 |  SI1905DL-T1-GE3 |  SI1906DL-T1 |
|  SI1912EDH |  SI1912EDH-T1 |  SI1912EDH-T1-E3 |  SI1912EDH-T1-E3 |  SI1912EDH-T1-GE3 |
|  SI1913DH-T1-E3 |  SI1913DH-T1-E3 |  SI1913DH-T1-GE3 |  SI1913EDH-T1 |  SI1913EDH-T1-E3 |
|  SI1913EDH-T1-E3 |  SI1913EDH-T1-GE3 |  SI1917EDH-T1 |  SI1917EDH-T1-E3 |  SI1917EDH-T1-E3 |
|  SI1917EDH-T1-GE3 |  SI1922EDH-T1-GE3 |  SI1922EDH-T1-GE3 |  SI1926DL-T1-E3 |  SI1926DL-T1-E3 |
|  SI1926DL-T1-GE3 |  SI1926DL-T1-GE3 |  SI1958DH-T1-E3 |  SI1958DH-T1-E3 |  SI1965DH-E3 |
|  SI1965DH-T1-E3 |  SI1965DH-T1-E3 |  SI1965DH-T1-GE3 |  SI1965DH-T1-GE3 |  SI1967DH-T1-E3 |
|  SI1967DH-T1-E3 |  SI1967DH-T1-GE3 |  SI1969DH-E3 |  SI1970DH-T1-GE3 |  SI1970DH-T1-GE3 |
|  SI1972DH-T1 |  SI1972DH-T1-E3 |  SI1972DH-T1-E3 |  SI1972DH-T1-GE |  SI1972DH-T1-GE3 |
|  SI1972DH-T1-GE3 |  SI1973DH-E3 |  SI1983DT-285-T1-E3 |  SI1988DH-T1-GE3 |  SI1988DH-T1-GE3 |

Contact us: Info@Y-IC.com

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